. . eescale Semiconductor Technical Data

Document Number: MHW8182C Rev. 2, 4/2006

Replaced by MHW8182CN. There are no form, fit or function changes with this part replacement. N suffix indicates RoHS compliant part.

CATV Amplifier Module

Features

- Specified for 77-, 110- and 128-Channel Loading
- Excellent Distortion Performance
- Superior Gain, Return Loss and DC Current Stability over Temperature
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

Applications

DRMA

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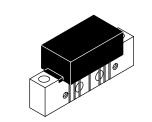
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ARCHIVE

- CATV Systems Operating in the 40 to 860 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk
 Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications
- Output Stage Amplifier on Applications Requiring Low Power Dissipation **Description**
- 24 Vdc Supply, 40 to 860 MHz, CATV Forward Amplifier Module



860 MHz 19.1 dB GAIN 128-CHANNEL CATV AMPLIFIER MODULE



CASE 1302-01, STYLE 1

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V _{in}	+70	dBmV
DC Supply Voltage	V _{CC}	+28	Vdc
Operating Case Temperature Range	Т _С	-20 to +100	°C
Storage Temperature Range	T _{stg}	-40 to +100	°C

Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_C = +30°C, 75 Ω system unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
Frequency Range		BW	40	_	860	MHz
Power Gain	50 MHz 860 MHz	G _p	18 18.2	18.5 19.1	19 20.5	dB
Slope 40 - 860 MHz		S	0	0.7	2.5	dB
Gain Flatness (40 - 860 MHz, Peak to Va	- Flatness (40 - 860 MHz, Peak to Valley)		—	0.3	0.6	dB
Return Loss — Input/Output (Z _o = 75 Ohms)		IRL/ORL				JD
	@ 40 MHz @ f > 40 MHz (Derate)		20	_	0.005	dB dB/MHz
Composite Second Order						dBc
(V _{out} = +38 dBmV/ch., Worst Case)	128-Channel FLAT	CSO ₁₂₈		-71	-64	
(V _{out} = +40 dBmV/ch., Worst Case)	110-Channel FLAT	CSO ₁₁₀	—	-70	-63	
(V _{out} = +44 dBmV/ch., Worst Case) 77-Channel FLAT		CSO ₇₇		-70	-64	

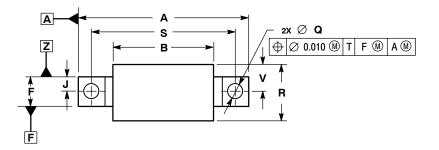




Characteristic		Symbol	Min	Тур	Max	Unit
Cross Modulation Distortion @ Ch 2						dBc
(V _{out} = +38 dBmV/ch., FM = 55 MHz)	128-Channel FLAT	XMD ₁₂₈		-68	-65	
$(V_{out} = +40 \text{ dBmV/ch.}, \text{FM} = 55 \text{ MHz})$	110-Channel FLAT	XMD ₁₁₀		-66	-64	
(V _{out} = +44 dBmV/ch., FM = 55 MHz)	77-Channel FLAT	XMD ₇₇		-61	-59	
Composite Triple Beat						dBc
(V _{out} = +38 dBmV/ch., Worst Case)	128-Channel FLAT	CTB ₁₂₈		-69	-66	
(V _{out} = +40 dBmV/ch., Worst Case)	110-Channel FLAT	CTB ₁₁₀		-68	-66	
(V _{out} = +44 dBmV/ch., Worst Case)	77-Channel FLAT	CTB ₇₇		-66	-64	
Noise Figure	50 MHz	NF		4.0	5.0	dB
	550 MHz			4.5	—	
	750 MHz			5.0	6.5	
	860 MHz		—	5.5	7.5	
DC Current (V _{DC} = 24 V, T _C = 30° C)		I _{DC}	180	220	240	mA



PACKAGE DIMENSIONS



NOTES:

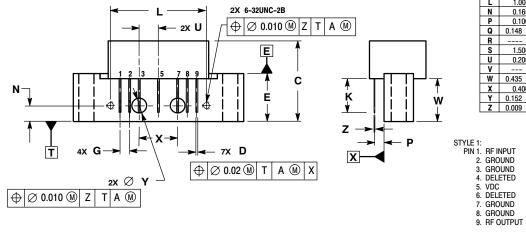
CONTROLLING DIMENSION: INCH.
 INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
C		0.840		21.336	
D	0.015	0.021	0.381	0.533	
E	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.620	8.255	
G	0.100 BSC		2.540 BSC		
J	0.156	6 BSC	3.962	BSC	
K	0.315	0.355	8.001	9.017	
L	1.000 BSC		25.400 BSC		
N	0.165 BSC		4.191 BSC		
Р	0.100 BSC		2.540 BSC		
Q	0.148	0.168	3.759	4.267	
R		0.600		15.240	
S	1.500 BSC		38.100 BSC		
U	0.200 BSC		5.080 BSC		
V		0.250		6.350	
W	0.435		11.049		
X	0.400 BSC		10.160 BSC		
Y	0.152	0.163	3.861	4.140	
Z	0.009	0.011	0.229	0.279	

ARCHIVE INFORMATION

RF Device Data

Freescale Semiconductor



CASE 1302-01 **ISSUE E**



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